TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS127D

February 1998 - Revised May 2004

Features

- Typical Propagation Delay: 6ns at V_{CC} = 5V, C_L = 15pF, T_A = 25^oC, Fastest Part in QMOS Line
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HCU Types
 - 2-V to 6-V Operation
 - High Noise Immunity: N_{IL} = 20%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

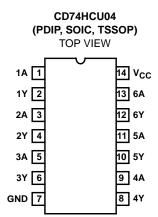
The CD74HCU04 unbuffered hex inverter utilizes silicon-gate CMOS technology to achieve operation speeds similar to LSTTL gates, with the low power consumption of standard CMOS integrated circuits. These devices especially are useful in crystal oscillator and analog applications.

Ordering Information

PART NUMBER	TEMP. RANGE (^O C)	PACKAGE
CD74HCU04E	-55 to 125	14 Ld PDIP
CD74HCU04M	-55 to 125	14 Ld SOIC
CD74HCU04MT	-55 to 125	14 Ld SOIC
CD74HCU04M96	-55 to 125	14 Ld SOIC
CD74HCU04PWR	-55 to 125	14 Ld TSSOP

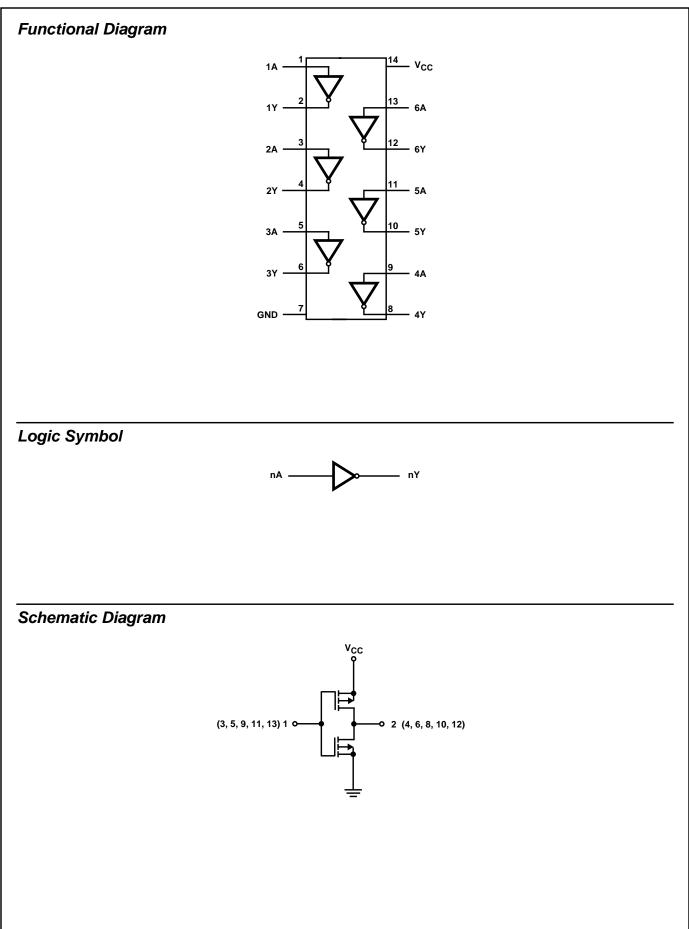
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a smallquantity reel of 250.

Pinout



CD74HCU04

High-Speed CMOS Logic Hex Inverter



Absolute Maximum Ratings

DC Supply Voltage, V _{CC} Voltages Referenced to Ground0.5V to +7V
DC Input Diode Current, I _{IK}
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Drain Current, per Output, I _O
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC} ±50mA

Operating Conditions

Temperature Range T _A	55 ⁰ C to 125 ⁰ C
Supply Voltage Range, V _{CC}	
DC Input or Output Voltage, VI, VO	\ldots 0V to V _{CC}

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (^o C/W)
E (PDIP) Package	80
M (SOIC) Package	86
PW (TSSOP) Package	113
Maximum Junction Temperature (Hermetic Package or Die)175 ⁰ C
Maximum Junction Temperature (Plastic Package)	150 ⁰ C
Maximum Storage Temperature Range65 ⁰	C to 150 ^o C
Maximum Lead Temperature (Soldering 10s)	300 ⁰ C
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating, and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS		25 ⁰ C		-40°C T	O +85 ⁰ C	-55°C TO 125°C		
PARAMETER	SYMBOL	V ₁ (V)	I _O (mA)	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
High Level Input	V _{IH}	-	-	2	1.7	-	1.7	-	1.7	-	V
Voltage				4.5	3.6	-	3.6	-	3.6	-	V
				6	4.8	-	4.8	-	4.8	-	V
Low Level Input	VIL	-	-	2	-	0.3	-	0.3	-	0.3	V
Voltage				4.5	-	0.8	-	0.8	-	0.8	V
				6	-	1.1	-	1.1	-	1.1	V
High Level Output	VOH	V _{IH or}	-0.02	2	1.8	-	1.8	-	1.8	-	V
Voltage CMOS Loads		V _{IL}	-0.02	4.5	4	-	4	-	4	-	V
0			-0.02	6	5.5	-	5.5	-	5.5	-	V
High Level Output		V _{CC} or	-4	4.5	3.98	-	3.84	-	3.7	-	V
Voltage TTL Loads		GND	-5.2	6	5.48	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH or}	0.02	2	-	0.2	-	0.2	-	0.2	V
Voltage CMOS Loads		VIL	0.02	4.5	-	0.5	-	0.5	-	0.5	V
0			0.02	6	-	0.5	-	0.5	-	0.5	V
Low Level Output			4	4.5	-	0.26	-	0.33	-	0.4	V
Voltage TTL Loads		V _{CC} or GND	5.2	6	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} or GND	-	6	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	2	-	20	-	40	μA

Switching Specifications Input t_r, t_f = 6ns

		TEST	v _{cc}	25 ⁰			-40 ⁰ C T	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	70	-	90	-	105	ns
Input to Output Y (Figure 1)		C _L = 50pF	4.5	-	-	14	-	18	-	21	ns
		C _L = 15pF	5	-	5	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	12	-	15	-	18	ns
Transition Times (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	18	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	CI	-				Se	e Figure	3		•	pF
Power Dissipation Capacitance (Notes 2, 3)	C _{PD}	-	5	-	14	-	-	-	-	-	pF

NOTES:

2. C_{PD} is used to determine the dynamic power consumption, per inverter.

3. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms

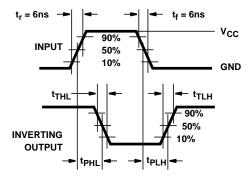
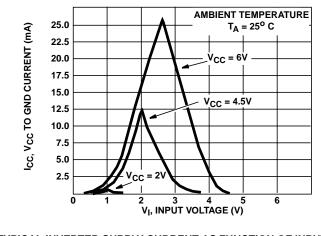


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

Typical Performance Curves





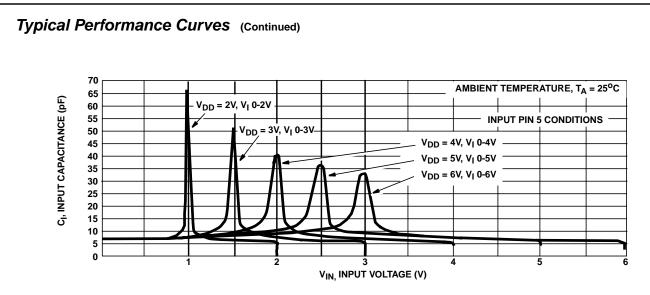


FIGURE 3. INPUT CAPACITANCE AS A FUNCTION OF INPUT VOLTAGE



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(1)		j			(2)	(6)	(5)		(4/3)	
CD74HCU04E	ACTIVE	PDIP	Ν	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCU04E	Samples
CD74HCU04EE4	ACTIVE	PDIP	Ν	14	25	TBD	Call TI	Call TI	-55 to 125		Samples
CD74HCU04M	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCU04M	Samples
CD74HCU04M96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCU04M	Samples
CD74HCU04M96E4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCU04M	Samples
CD74HCU04M96G4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCU04M	Samples
CD74HCU04PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJU04	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD74HCU04 :

Automotive : CD74HCU04-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

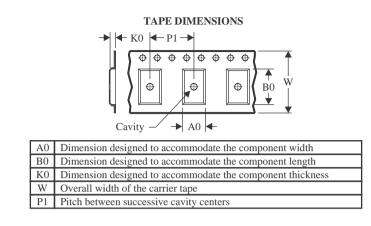


Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HCU04M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCU04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HCU04M96	SOIC	D	14	2500	356.0	356.0	35.0
CD74HCU04PWR	TSSOP	PW	14	2000	356.0	356.0	35.0

TEXAS INSTRUMENTS

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TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD74HCU04E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HCU04E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HCU04EE4	N	PDIP	14	25	506	13.97	11230	4.32
CD74HCU04EE4	N	PDIP	14	25	506	13.97	11230	4.32
CD74HCU04M	D	SOIC	14	50	506.6	8	3940	4.32

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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